NPN 2.0A 60V Middle Power Transistor

Parameter	Value
V_{CEO}	60V
I _C	2.0A

Features

1) Suitable for Middle Power Driver

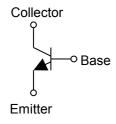
2) Complementary PNP Types: 2SB1561

3) Low V_{CE(sat)}

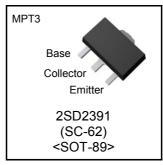
 $V_{CE(sat)}$ =0.35V(Max.) (I_C/I_B =1A/50mA)

4) Lead Free/RoHS Compliant.

•Inner circuit



Outline



Applications

Motor driver , LED driver Power supply

Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
2SD2391	MPT3	4540	T100	180	12	1,000	DT

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Values	Unit
Collector-base voltage		V_{CBO}	60	V
Collector-emitter voltage		V _{CEO}	60	V
Emitter-base voltage		V _{EBO}	6	V
Collector current	DC	I _C	2.0	Α
	Pulsed	I _{CP} *1	6.0	Α
Power dissipation		P _D *2	0.5	W
		P _D *3	2.0	W
Junction temperature		Tj	150	°C
Range of storage temperature		T _{stg}	−55 to +150	°C

^{*1} Pw=10ms, single pulse

●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	BV _{CEO}	I _C = 1mA	60	-	-	V
Collector-base breakdown voltage	BV _{CBO}	I _C = 50μA	60	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = 50μA	6	ı	-	V
Collector cut-off current	I _{CBO}	V _{CB} = 50V	ı	ı	0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} = 5V	ı	ı	0.1	μΑ
Collector-emitter saturation voltage	V _{CE(sat)} *4	I _C = 1A, I _B = 50mA	ı	0.13	0.35	V
DC current gain	h _{FE1}	$V_{CE} = 2V, I_{C} = 0.5A$	120	ı	270	-
Do current gain	h _{FE2}	$V_{CE} = 2V, I_{C} = 1.5A$	45	-	-	-
Transition frequency	f_**4	$V_{CE} = 2V, I_{E} = -500 \text{mA}$ f=100MH _Z	-	210	-	MHz
Output capacitance	C _{ob}	$V_{CB} = 10V, I_{E} = 0A,$ f = 1MHz	ı	21	-	pF

^{*4} Pulsed

●h_{FE} rank categories

Rank	Q		
h _{FE}	120 to 270		

2/6

^{*2} Each terminal mounted on a reference land

^{*3} Mounted on a ceramic board (40×40×0.7mm)

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Ground Emitter Propagation Characteristics

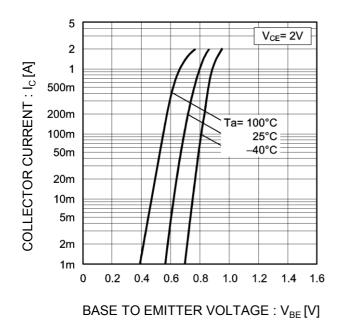
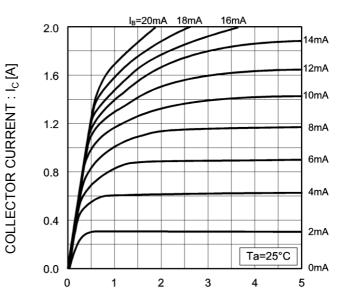


Fig.2 Typical Output Characteristics



COLECTOR TO EMITTE VOLTAGE : $V_{CE}[V]$

Fig.3 DC Current Gain vs. Collector Current(I)

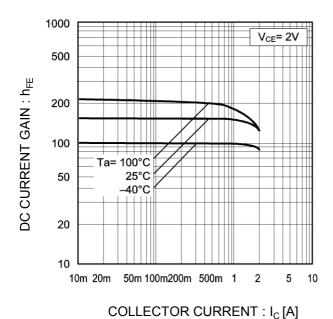
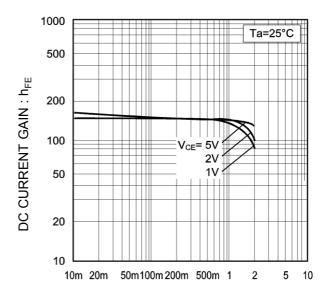


Fig.4 DC current gain vs. output current (II)



COLLECTOR CURRENT : I_C [A]

●Electrical characteristic curves(Ta = 25°C)

Fig.5 Collector-Emitter Saturation Voltage

vs. Collector Current (I) 1000 I_C/I_B=20 SATURATION VOLTAGE: V_{CE(sat)} [mV] 500 200 COLLECTOR-EMITTER 100 50 100°C 25°C -40°C 20 10 5 2 5m 10m 20m 50m100m200m 500m 1

Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current (II) 1000 Ta=25°C $\label{eq:collector-emitter} SATURATION \ VOLTAGE: V_{CE(sat)} \ [mV]$ 500 200 100 50 $I_{\rm C}/I_{\rm B} = 50$ 20 20 10 10 5 2 5m 10m 20m 50m100m200m 500m 1 5

COLLECTOR CURRENT : I_C [A]

COLLECTOR CURRENT : $I_C[A]$

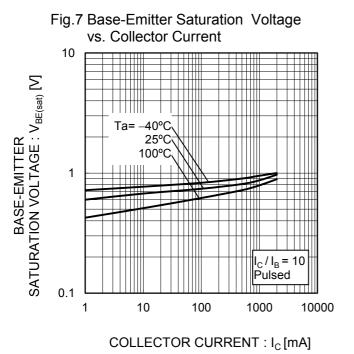


Fig.8 Gain Bandwidth Product vs. Emitter Current 1000 Ta= 25°C 500 V_{CE}= 2V TRANSITION FREQUENCY: fr [MHz] 200 100 50 20 10 5 2 -100m -2m -10m -2

EMITTER CURRENT : I_E [A]

2

0.1 0.2

0.5

●Electrical characteristic curves(Ta = 25°C)

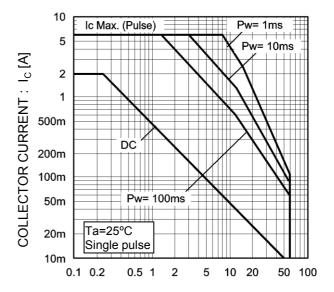
Fig.9 Emitter input capacitance vs. **Emitter-Base Voltage** Collector output capacitance vs. Collector-Base Voltage COLLECTOR OUTPUT CAPACITANCE: Cob [pF] EMITTER INPUT CAPACITANCE: Cib [pF] 1000 Ta= 25°C 500 f=1MHz C_{ib} I_E=0A I_C=0A 200 100 50 20 Cob 10 5

COLLECTOR - BASE VOLTAGE : $V_{CB}\left[V\right]$ EMITTER - BASE VOLTAGE : VEB [V]

5 10 20 50 100

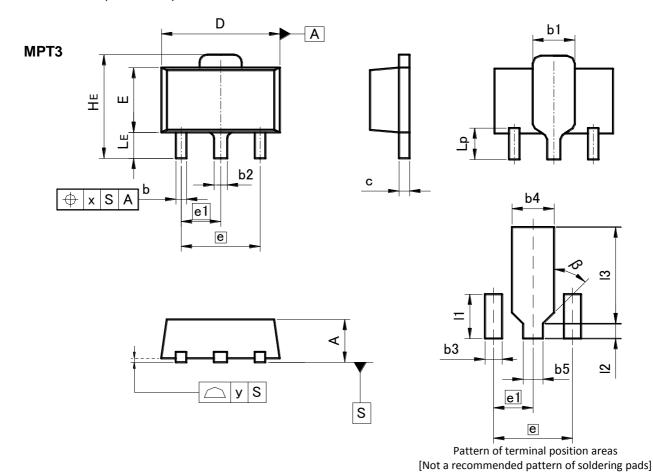
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Fig.10 Safe Operating Area



COLLECTOR TO EMITTER VOLTAGE: V_{CE} [V]

●Dimensions (Unit : mm)



DIM	MILIM	ETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	1.40	1.50	0.055	0.059	
b	0.30	0.50	0.012	0.020	
b1	1.50	1.70	0.059	0.067	
b2	0.40	0.60	0.016	0.024	
С	0.35	0.50	0.014	0.020	
D	4.40	4.70	0.173	0.185	
Е	2.40	2.70	0.094	0.106	
е	3.0	00 0.118		18	
e1	1.50		0.059		
HE	3.70	4.30	0.146	0.169	
LE	0.80	1.20	0.031	0.047	
Lp	1.01	1.41	0.040	0.056	
Х	_	0.15	_	0.006	
У	_	0.10	_	0.004	

DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
b3	_	0.65	-	0.026	
b4	-	1.70	-	0.067	
b5	-	0.75	-	0.030	
11	-	1.71	ı	0.067	
12	-	0.58	I	0.023	
13	_	3.72	-	0.146	
β	45°		45°		

Dimension in mm / inches

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